National Semiconductor

March 1993

54AC/74AC821 • 54ACT/74ACT821
10-Bit D Flip-Flop with TRI-STATE® Outputs

General Description

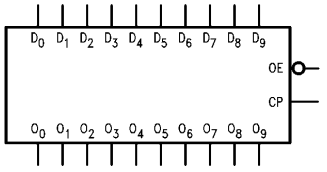
The 'AC/'ACT821 is a 10-bit D flip-flop with TRI-STATE outputs arranged in a broadside pinout.

The 'AC/'ACT821 is functionally identical to the AM29821.

Features

- TRI-STATE outputs for bus interfacing
- Noninverting outputs
- Outputs source/sink 24 mA
- 'ACT821 has TTL-compatible inputs
- Standard Military Drawing (SMD)
  — 'ACT821: 5962-88705

Logic Symbols



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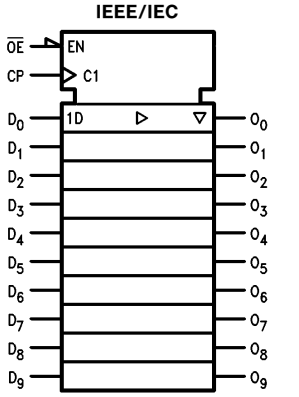

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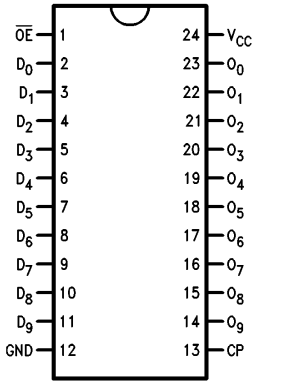
Pin Names	Description
D_0–D_9	Data Inputs
O_0–O_9	Data Outputs
$\overline{OE}$	Output Enable Input
CP	Clock Input

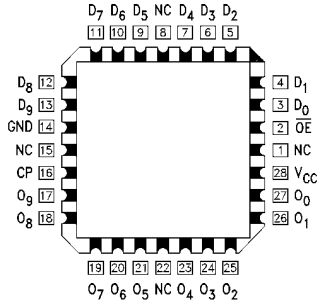
Connection Diagrams

Pin Assignment for DIP, Flatpak and SOIC



TL/F/10139–3

Pin Assignment for LCC



TL/F/10139–4

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RRD-B30M75/Printed in U. S. A.

Functional Description

The ’AC/’ACT821 consists of ten D-type edge-triggered flip-flops. The buffered Clock (CP) and buffered Output Enable ($\overline{OE}$) are common to all flip-flops. The flip-flops will store the state of their individual D inputs that meet the setup and hold time requirements on the LOW-to-HIGH CP transition. With $\overline{OE}$ LOW the contents of the flip-flops are available at the outputs. When $\overline{OE}$ is HIGH the outputs go to the high impedance state. Operation of the $\overline{OE}$ input does not affect the state of the flip-flops.

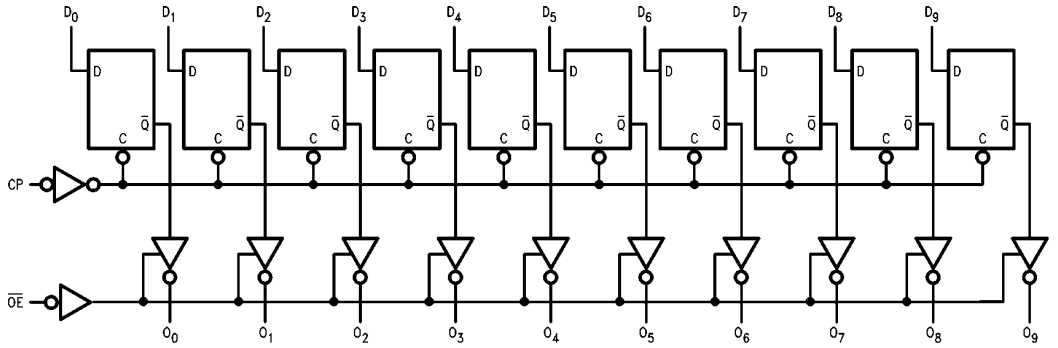
The ’AC/’ACT821 is functionally and pin compatible with the AM29821.

Function Table

Inputs			Internal	Outputs	Function
$\overline{OE}$	CP	D	Q	O	
H	⌐⌐	L	L	Z	High Z
H	⌐⌐	H	H	Z	High Z
L	⌐⌐	L	L	L	Load
L	⌐⌐	H	H	H	Load

H = HIGH Voltage Level
L = LOW Voltage Level
Z = HIGH Impedance
⌐⌐ = LOW-to-HIGH Clock Transition

Logic Diagram



TL/F/10139–5

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Rating (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
$V_I = -0.5V$	−20 mA
$V_I = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
$V_O = -0.5V$	−20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})	±50 mA
Storage Temperature (T_{STG})	−65°C to +150°C
Junction Temperature (T_J)	
CDIP	175°C
PDIP	140°C

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Recommended Operating Conditions

Supply Voltage (V_{CC})	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	
74AC/ACT	−40°C to +85°C
54AC/ACT	−55°C to +125°C
Minimum Input Edge Rate ($\Delta V/\Delta t$) 'AC Devices V_{IN} from 30% to 70% of V_{CC} V_{CC} @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ($\Delta V/\Delta t$) 'ACT Devices V_{IN} from 0.8V to 2.0V V_{CC} @ 4.5V, 5.5V	125 mV/ns

DC Characteristics for 'AC Family Devices

Symbol	Parameter	V_{CC} (V)	74AC $T_A = +25°C$		54AC $T_A = -55°C$ to $+125°C$	74AC $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits				
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.1	2.1	2.1	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	3.15	3.15	3.15		
		5.5	2.75	3.85	3.85	3.85		
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.9	0.9	0.9	V	$V_{OUT} = 0.1V$ or $V_{CC} - 0.1V$
		4.5	2.25	1.35	1.35	1.35		
		5.5	2.75	1.65	1.65	1.65		
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	2.9	V	$I_{OUT} = -50\ \mu A$
		4.5	4.49	4.4	4.4	4.4		
		5.5	5.49	5.4	5.4	5.4		
		3.0		2.56	2.4	2.46	V	*$V_{IN} = V_{IL}$ or V_{IH} I_{OH} −12 mA
		4.5		3.86	3.7	3.76		I_{OH} −24 mA
		5.5		4.86	4.7	4.76		−24 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	0.1	V	$I_{OUT} = 50\ \mu A$
		4.5	0.001	0.1	0.1	0.1		
		5.5	0.001	0.1	0.1	0.1		
		3.0		0.36	0.50	0.44	V	*$V_{IN} = V_{IL}$ or V_{IH} I_{OL} 12 mA
		4.5		0.36	0.50	0.44		I_{OL} 24 mA
		5.5		0.36	0.50	0.44		24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	$V_I = V_{CC}$, GND

*All outputs loaded; thresholds on input associated with output under test.

DC Characteristics for 'AC Family Devices (Continued)

Symbol	Parameter	V_{CC} (V)	74AC $T_A = +25°C$		54AC $T_A = -55°C$ to $+125°C$	74AC $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits				
I_{OZ}	Maximum TRI-STATE® Current	5.5		±0.5	±10.0	±5.0	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
I_{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	μA	V_{IN} = V_{CC} or GND

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.
I_{CC} for 54AC @ 25°C is identical to 74AC @ 25°C.

DC Characteristics for 'ACT Family Devices

Symbol	Parameter	V_{CC} (V)	74ACT $T_A = +25°C$		54ACT $T_A = -55°C$ to $+125°C$	74ACT $T_A = -40°C$ to $+85°C$	Units	Conditions
			Typ	Guaranteed Limits				
V_{IH}	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	2.0 2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	0.8 0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	4.4 5.4	V	I_{OUT} = −50 μA
		4.5 5.5		3.86 4.86	3.70 4.70	3.76 4.76	V	*V_{IN} = V_{IL} or V_{IH} I_{OH} −24 mA I_{OH} −24 mA
V_{OL}	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	0.1 0.1	V	I_{OUT} = 50 μA
		4.5 5.5		0.36 0.36	0.50 0.50	0.44 0.44	V	*V_{IN} = V_{IL} or V_{IH} I_{OL} 24 mA I_{OL} 24 mA
I_{IN}	Maximum Input Leakage Current	5.5		±0.1	±1.0	±1.0	μA	V_I = V_{CC}, GND
I_{OZ}	Maximum TRI-STATE® Current	5.5		±0.5	±10.0	±5.0	μA	V_I = V_{IL}, V_{IH} V_O = V_{CC}, GND
I_{CCT}	Maximum I_{CC}/Input	5.5	0.6		1.6	1.5	mA	V_I = V_{CC} − 2.1V
I_{OLD}	†Minimum Dynamic Output Current	5.5			50	75	mA	V_{OLD} = 1.65V Max
I_{OHD}		5.5			−50	−75	mA	V_{OHD} = 3.85V Min
I_{CC}	Maximum Quiescent Supply Current	5.5		8.0	160.0	80.0	μA	V_{IN} = V_{CC} or GND

*All outputs loaded; thresholds on input associated with output under test.

†Maximum test duration 2.0 ms, one output loaded at a time.

Note: I_{CC} for 54ACT @ 25°C is identical to 74ACT @ 25°C.

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF			54AC $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
f_{max}	Maximum Clock Frequency	3.3 5.0	110 120	145 160		95 100		100 110		MHz
t_{PLH}	Propagation Delay CP to O_n	3.3 5.0	3.0 2.0	8.0 6.0	13.0 9.5	1.0 1.5	13.0 9.5	3.0 2.0	15.0 10.5	ns
t_{PHL}	Propagation Delay CP to O_n	3.3 5.0	3.0 2.0	8.0 5.5	13.0 9.5	1.0 1.5	13.0 9.5	3.0 2.0	15.0 10.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	3.3 5.0	2.5 1.5	6.0 4.5	11.0 8.0	1.0 1.5	13.0 9.5	2.5 1.5	12.0 9.0	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	3.3 5.0	2.5 1.5	6.5 5.0	11.0 8.0	1.0 1.5	13.0 9.5	2.5 1.5	12.0 9.0	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	3.3 5.0	2.5 1.5	6.5 5.0	10.5 8.0	1.0 1.5	12.0 10.0	2.5 1.5	11.0 8.5	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	3.3 5.0	2.5 1.5	6.0 4.5	10.5 8.0	1.0 1.5	12.0 10.0	2.5 1.5	11.0 8.5	ns

*Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74AC $T_A = +25°C$, $C_L = 50$ pF		54AC $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF	74AC $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW D_n to CP	3.3 5.0	−1.0 −1.0	1.5 1.5	3.0 3.0	1.5 1.5	ns
t_h	Hold Time, HIGH or LOW D_n to CP	3.3 5.0	−1.0 −1.0	3.5 3.5	3.0 3.0	4.0 4.0	ns
t_w	CP Pulse Width HIGH or LOW	3.3 5.0	3.5 2.5	5.0 4.0	6.0 5.0	5.5 4.0	ns

*Voltage Range 3.3 is 3.3V ±0.3V
Voltage Range 5.0 is 5.0V ±0.5V

AC Electrical Characteristics

Symbol	Parameter	V_{CC}* (V)	74ACT $T_A = +25°C$, $C_L = 50$ pF			54ACT $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF		74ACT $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	Min	Max	
f_{max}	Maximum Clock Frequency	5.0	120	150		85		110		MHz
t_{PLH}	Propagation Delay CP to O_n	5.0	2.0	6.0	9.5	1.5	11.5	1.5	10.5	ns
t_{PHL}	Propagation Delay CP to O_n	5.0	2.5	6.0	9.5	1.5	11.5	2.0	10.5	ns
t_{PZH}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.0	10.5	1.5	12.5	2.0	11.5	ns
t_{PZL}	Output Enable Time $\overline{OE}$ to O_n	5.0	2.5	7.0	10.5	1.5	13.0	2.0	12.0	ns
t_{PHZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	7.5	12.0	1.5	13.5	1.0	13.0	ns
t_{PLZ}	Output Disable Time $\overline{OE}$ to O_n	5.0	1.5	7.0	10.5	1.5	12.5	1.0	11.5	ns

*Voltage Range 5.0 is 5.0V ±0.5V

AC Operating Requirements

Symbol	Parameter	V_{CC}* (V)	74ACT $T_A = +25°C$, $C_L = 50$ pF		54ACT $T_A = -55°C$ to $+125°C$, $C_L = 50$ pF	74ACT $T_A = -40°C$ to $+85°C$, $C_L = 50$ pF	Units
			Typ	Guaranteed Minimum			
t_s	Setup Time, HIGH or LOW D_n to CP	5.0	2.5	2.0	4.0	2.5	ns
t_h	Hold Time, HIGH or LOW D_n to CP	5.0	−0.5	2.0	3.0	2.5	ns
t_w	CP Pulse Width HIGH or LOW	5.0	3.0	4.5	6.0	5.5	ns

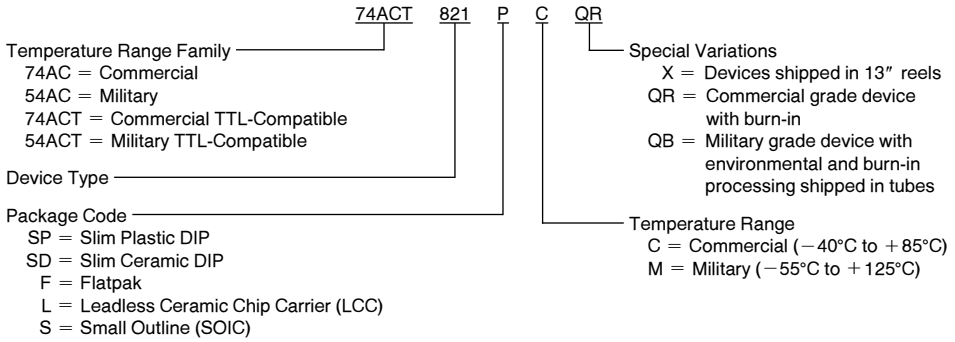
*Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

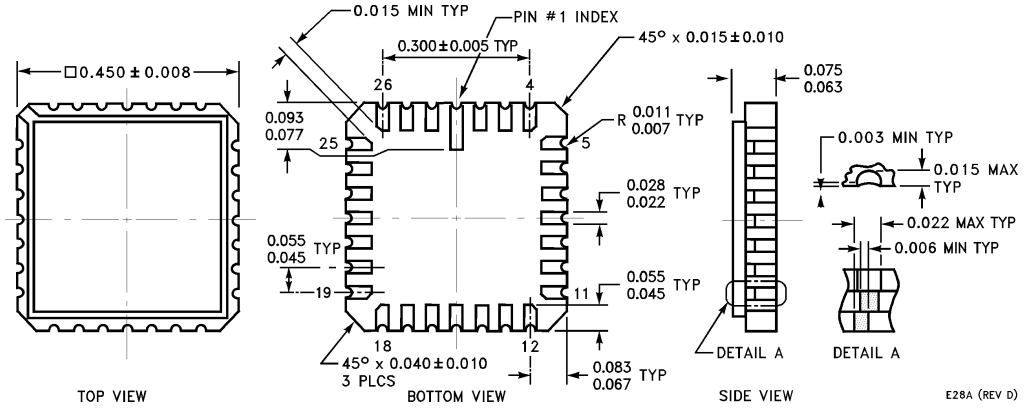
Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = OPEN
C_{PD}	Power Dissipation Capacitance	35.0	pF	V_{CC} = 5.0V

Ordering Information

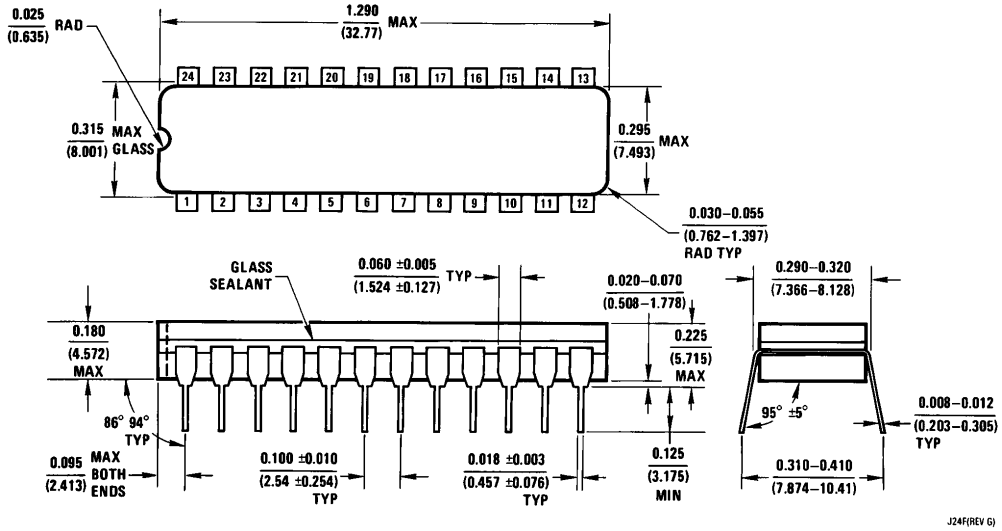
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)

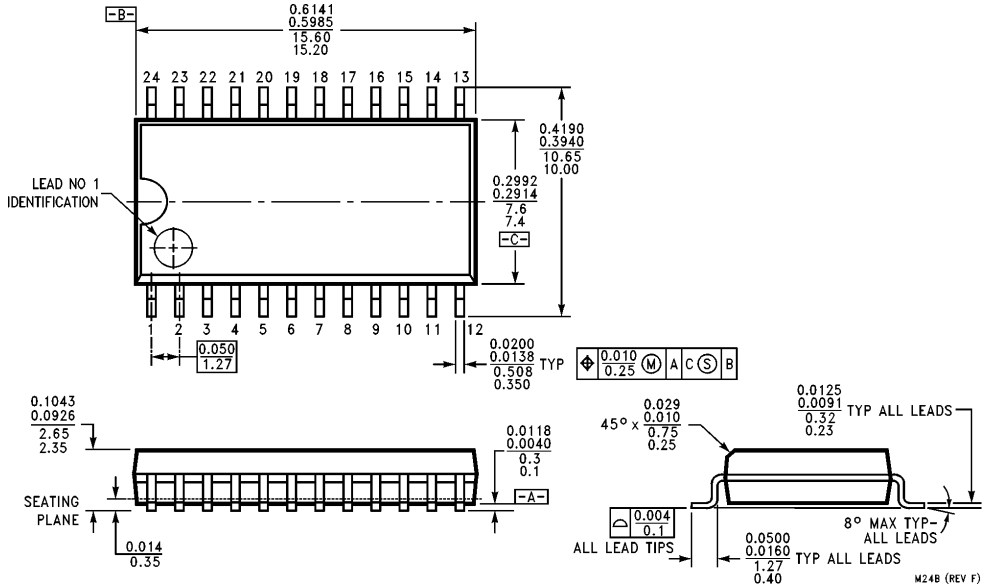


28 Terminal Ceramic Leadless Chip Carrier (L)
NS Package Number E28A

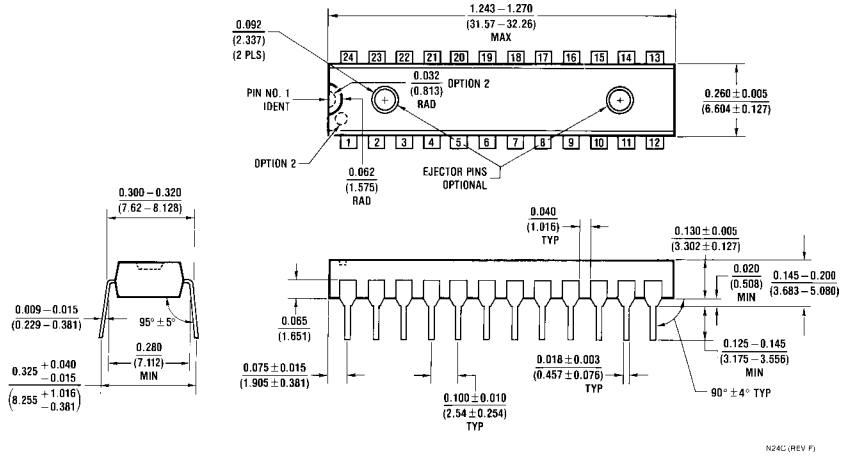


24 Lead Slim (0.300″ Wide) Ceramic Dual-In-Line Package (SD)
NS Package Number J24F

Physical Dimensions inches (millimeters) (Continued)

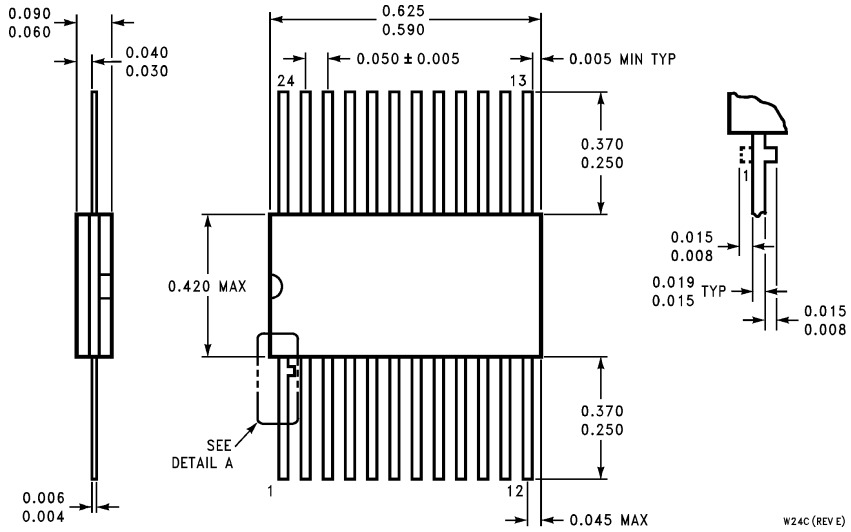


24 Lead Small Outline Integrated Circuit (S)
NS Package Number M24B



24 Lead Slim (0.300″ Wide) Plastic Dual-In-Line Package (SP)
NS Package Number N24C

Physical Dimensions inches (millimeters) (Continued)



24 Lead Ceramic Flatpak (F)
NS Package Number W24C

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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